

# HAC RF TESTREPORT

# No. I17Z60505-SEM02

For

TCL Communication Ltd.

## GSM Quad-band/UMTS Quad-band CDMA/EVDO Tri-band

/LTE 13 bands mobile phone

Modelname: 6060S

With

**Hardware Version: 04** 

Software Version: v4E1W

FCC ID: 2ACCJA024

**Results Summary: M Category = M4** 

Issued Date: 2017-5-10



#### Note:

The test results in this test report relate only to the devices specified in this report. This report shall not be reproduced except in full without the written approval of CTTL.

#### **Test Laboratory:**

CTTL, Telecommunication Technology Labs, Academy of Telecommunication Research, MIIT No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District, Beijing, P. R. China100191 Tel:+86(0)10-62304633-2512,Fax:+86(0)10-62304633-2504

Email:cttl terminals@catr.cn, website:www.chinattl.com



# **REPORT HISTORY**

Report Number	Revision	Issue Date	Description
I17Z60505-SEM02	Rev.0	2017-5-10	Initial creation of test report



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# 1 Test Laboratory

## 1.1 Testing Location

CompanyName:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

## **1.2 Testing Environment**

Temperature:	18°C~25°C,		
Relative humidity:	30%~ 70%		
Ground system resistance: $< 0.5 \Omega$			
Ambient noise is checked and found very low and in compliance with requirement of standards			

Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.

## 1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Hao
Testing Start Date:	April 26, 2017
Testing End Date:	April 26, 2017

## 1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Lu Bingsong

**Deputy Director of the laboratory** 

(Approved this test report)



# **2 Client Information**

## 2.1 Applicant Information

Company Name:	TCL Communication Ltd.
Address (Deet	5F, C building, No. 232, Liang Jing Road ZhangJiang High-Tech Park,
Address /Post:	Pudong Area Shanghai, P.R. China. 201203
City:	Shanghai
Postal Code:	201203
Country:	P.R.China
Contact:	Gong Zhizhou
Email:	zhizhou.gong@tcl.com
Telephone:	0086-21- 31363544
Fax:	0086-21-61460602

## 2.2 Manufacturer Information

Company Name:	TCL Communication Ltd.
Address (Deet	5F, C building, No. 232, Liang Jing Road ZhangJiang High-Tech Park,
Address /Post:	Pudong Area Shanghai, P.R. China. 201203
City:	Shanghai
Postal Code:	201203
Country:	P.R.China
Contact:	Gong Zhizhou
Email:	zhizhou.gong@tcl.com
Telephone:	0086-21- 31363544
Fax:	0086-21-61460602



## 3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

#### 3.1 About EUT

Description:	GSM Quad-band/UMTS Quad-band CDMA/EVDO Tri-band /LTE 13
	bands mobile phone
Model name:	6060S
Operating mode(s):	GSM 850/900/1800/1900, UMTS FDD 1/2/4/5/, BT, Wi-Fi LTE Band 1/2/3/4/5/7/12/13/17/25/26/41/66, CDMA BC0/1/10

## 3.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	014909000006516	04	v4E1W
EUT2	014909000009528	04	v4E1W

<sup>\*</sup>EUT ID: is used to identify the test sample in the lab internally.

Note: It is performed to test HAC with the EUT1 and conducted power with the EUT2.

## 3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	CAC2560001CJ	1	COSLIGHT
AE2	Battery	CAC2560002C1	1	BYD

<sup>\*</sup>AE ID: is used to identify the test sample in the lab internally.

**Note:** It is performed to test HAC with the AE1.

## 3.4 Air Interfaces / Bands Indicating Operating Modes

Air-interface	Band(MHz)	Туре	C63.19/tested	Simultaneous Transmissions	ОТТ	Power Reduction
CDMA	CDMA BC0/1/10	VO	Yes	BT, WLAN	NA	NA
GSM	850	VO	Yes	BT, WLAN	NA	NA
OOW	1900	VO	103			INA
GPRS/EDGE	850	DT	NA			No
GFR3/EDGE	1900	וט				INO
	850	VO	Yes	BT, WLAN	NA	
WCDMA	1700					NA
(UMTS)	1900					
	HSPA	DT	NA			
LTE	Band 2/4/5/7/12/13/ 25/26/41	V/D.	NA	BT, WLAN	NA	NA
ВТ	2450	DT	NA	GSM, WCDMA, LTE	NA	NA
WLAN	2450	DT	NA	GSM, WCDMA, LTE	NA	NA

VO: Voice CMRS/PSTN Service Only V/D: Voice CMRS/PSTN and Data Service DT: Digital Transport

Note:1.= No Associated T-Coil measurement has been made in accordance with 285076 D02 T-Coil testing for CMRS IP

<sup>\*</sup> HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating



## **4 CONDUCTED OUTPUT POWER MEASUREMENT**

### 4.1 Summary

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

#### **4.2 Conducted Power**

GSM	Conducted Power (dBm)				
850MHz	Channel 251(848.8MHz)	Channel 190(836.6MHz)	Channel 128(824.2MHz)		
OSUWINZ	32.89	32.87	33.01		
GSM		Conducted Power(dBm)			
1900MHz	Channel 810(1909.8MHz)	Channel 661(1880MHz)	Channel 512(1850.2MHz)		
1900IVITZ	30.14	30.04	30.02		
WCDMA	Conducted Power (dBm)				
850MHz	Channel 4233(846.6MHz)	Channel 4182(836.4MHz)	Channel 4132(826.4MHz)		
OOUWINZ	23.76	23.64	23.89		
WCDMA	Conducted Power (dBm)				
WCDMA	Channel 1513 (1752.6MHz)	Channel 1412 (1732.4MHz)	Channel 1312 (1712.4MHz)		
1700MHz	23.87	23.91	23.45		
WCDMA	Conducted Power (dBm)				
	Channel 9538(1907.6MHz)	Channel 9400(1880MHz)	Channel 9262(1852.4MHz)		
1900MHz	23.48	23.66	23.81		

LTE	Conducted Power (dBm)			
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)	
QPSK	23.89	23.59	23.45	
LTE		Conducted Power (dBm)		
Band4	Channel 20300(1745MHz)	Channel20175(1732.5MHz)	Channel 20050(1720MHz)	
QPSK	23.62	23.55	23.58	
LTE		Conducted Power (dBm)		
Band5	Channel 20600(844MHz)	Channel 20525(836.5MHz)	Channel20450(829MHz)	
QPSK	23.68	23.89	24.06	
LTE	Conducted Power (dBm)			
Band7	Channel 21350(2560MHz)	Channel21100(2535MHz)	Channel 20850(2510MHz)	
QPSK	23.91	23.75	24.00	
LTE		Conducted Power (dBm)		
Band12	Channel 23130(711MHz) Channel 23095(707.5MHz) Channel 23060		Channel23060(704MHz)	
QPSK	24.09	23.73	23.85	
LTE	Conducted Power (dBm)			
Band13		Channel 23230(782MHz)		



QPSK		23.80	
LTE	Conducted Power (dBm)		
Band17	Channel 23800(711MHz)	Channel 23790(710MHz)	Channel 23780(709MHz)
QPSK	23.50	23.72	23.65
LTE		Conducted Power (dBm)	
Band25	Channel 26590(1905MHz)	Channel 26365(1883MHz)	Channel 26140(1860MHz)
QPSK	24.00	23.70	23.91
LTE	Conducted Power (dBm)		
Band26	Channel 26965(841.5MHz)	Channel 26865(831.5MHz)	Channel 26775(822.5MHz)
QPSK	23.51	23.62	23.52
LTE		Conducted Power (dBm)	
Band41	Channel 41490(2680MHz)	Channel 40620(2593MHz)	Channel 39750(2506MHz)
QPSK	23.35	23.54	23.37
LTE	Conducted Power (dBm)		
Band66	Channel 132572(1770MHz)	Channel 132322(1745MHz)	Channel 132072(1720MHz)
QPSK	23.82	23.91	23.99

LTE		Conducted Power (dBm)		
Band2	Channel 19100(1900MHz)	Channel 19100(1900MHz)	Channel 19100(1900MHz)	
16-QAM	23.00	22.88	22.94	
LTE		Conducted Power (dBm)		
Band4	Channel 20300(1745MHz)	Channel 20300(1745MHz)	Channel 20300(1745MHz)	
16-QAM	22.97	23.02	22.81	
LTE		Conducted Power (dBm)		
Band5	Channel 20600(844MHz)	Channel 20600(844MHz)	Channel 20600(844MHz)	
16-QAM	22.81	23.09	23.18	
LTE		Conducted Power (dBm)		
Band7	Channel 21350(2560MHz)	Channel 21350(2560MHz)	Channel 21350(2560MHz)	
16-QAM	23.15	22.99	23.35	
LTE	Conducted Power (dBm)			
Band12	Channel 23130(711MHz)	Channel 23130(711MHz)	Channel 23130(711MHz)	
16-QAM	23.23	22.92	22.91	
LTE		Conducted Power (dBm)		
Band13		Channel 23230(782MHz)		
16-QAM		23.29		
LTE		Conducted Power (dBm)		
Band17	Channel 23800(711MHz)	Channel 23800(711MHz)	Channel 23800(711MHz)	
16-QAM	22.63	22.91	22.85	
LTE		Conducted Power (dBm)		
Band25	Channel 26590(1905MHz)	Channel 26590(1905MHz)	Channel 26590(1905MHz)	
16-QAM	23.19	22.82	22.91	
LTE		Conducted Power (dBm)		
Band26	Channel 26965(841.5MHz)	Channel 26965(841.5MHz)	Channel 26965(841.5MHz)	



16-QAM	22.64	22.68	22.69	
LTE	Conducted Power (dBm)			
Band41	Channel 41490(2680MHz)	Channel 41490(2680MHz)	Channel 41490(2680MHz)	
16-QAM	22.22	22.23	22.30	
LTE	Conducted Power (dBm)			
Band66	Channel 132572(1770MHz)	Channel 132572(1770MHz)	Channel 132572(1770MHz)	
16-QAM	23.38	23.31	23.43	

CDMA	Conducted Power (dBm)			
BC0	Channel 777 (848.31MHz)	Channel 384 (836.52MHz)	Channel 1013 (824.7MHz)	
ВСО	24.74	24.68	24.56	
CDMA	Conducted Power (dBm)			
CDMA BC1	Channel 1175 (1908.75MHz)	Channel 600 (1880MHz)	Channel 25 (1851.25MHz)	
ВСТ	24.33	24.34	24.41	
CDMA	Conducted Power (dBm)			
CDMA BC10	Channel 684 (832.1MHz)	Channel 580 (820.5MHz)	Channel 476(817.9MHz)	
5010	24.54	24.56	24.53	

## **5 Reference Documents**

## **5.1 Reference Documents for testing**

The following document listed in this section is referred for testing.

Reference	Title	Version	
ANSI C63.19-2011	American National Standard for Methods of Measurement of	2011	
	Compatibility between Wireless Communication Devices and	Edition	
	Hearing Aids		
FCC 47 CFR §20.19	Hearing Aid Compatible Mobile Headsets		
KDB 285076 D01	Equipment Authorization Guidance for Hearing Aid Compatibility	v04	



#### **6 OPERATIONAL CONDITIONS DURING TEST**

#### 6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick),and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core21.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE)circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

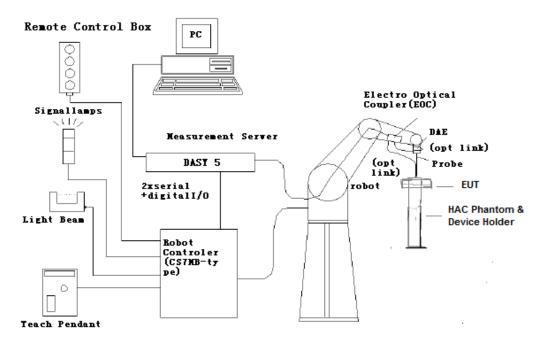


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



## **6.2 Probe Specification**

#### E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%,

k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity ± 0.2 dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms



[ER3DV6]



#### 6.3Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions:  $370 \times 370 \times 370 \text{ mm}$ ).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field  $<\pm 0.5$  dB.



Fig. 2 HAC Phantom & Device Holder

#### 6.4Robotic System Specifications

#### **Specifications**

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ±0.02 mm

No. of Axis: 6

## **Data Acquisition Electronic (DAE) System**

**Cell Controller** 

Processor: Intel Core2 Clock Speed: 1.86GHz

**Operating System:** Windows XP

**Data Converter** 

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

Connecting Lines: Optical downlink for data and status info.

Optical uplink for commands and clock



#### **7 EUT ARRANGEMENT**

#### 7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- •The measurement plane is located parallel to the reference plane and 15 mm from it, out from the phone. The grid is located in the measurement plane.

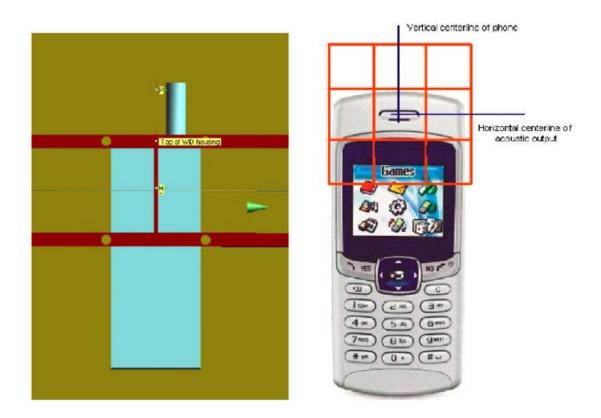


Fig. 3 WD reference and plane for RF emission measurements



#### 8 SYSTEM VALIDATION

#### 8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical output. Position the E-field probes so that:

- •The probes and their cables are parallel to the coaxial feed of the dipole antenna
- •The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 15 mm from the closest surface of the dipole elements.

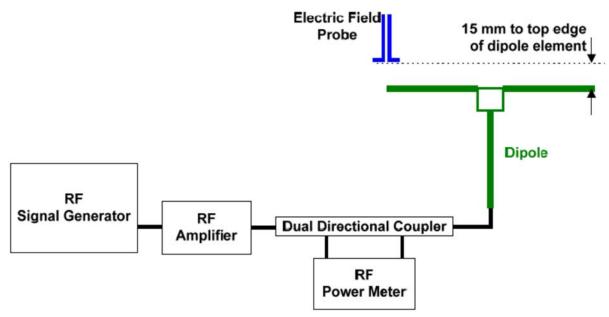


Fig. 4 Dipole Validation Setup

#### 8.2 Validation Result

	E-Field Scan					
Mode	Mode Frequency Input Power Measured <sup>1</sup> Target <sup>2</sup> Deviation <sup>3</sup> Limit <sup>4</sup>					
	(MHz)	(mW)	Value(dBV/m)	Value(dBV/m)	(%)	(%)
CW	835	100	40.50	40.54	-0.46	±25
CW	1880	100	39.47	39.35	1.39	±25

#### Notes:

- 1. Please refer to the attachment for detailed measurement data and plot.
- 2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
- 3. Deviation (%) = 100 \* (Measured value minus Target value) divided by Target value.
- 4. ANSI C63.19 requires values within  $\pm$  25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values independently validated for the dipole actually used in the measurements should be used, when available.



#### 9 Evaluation of MIF

#### 9.1 Introduction

The MIF (Modulation Interference Factor) is used to classify E-field emission to determine Hearing Aid Compatibility (HAC). It scales the power-averaged signal to the RF audio interference level and is characteristic to a modulation scheme. The HAC standard preferred "indirect" measurement method is based on average field measurement with separate scaling by the MIF. With an Audio Interference Analyzer (AIA) designed by SPEAG specifically for the MIF measurement, these values have been verified by practical measurements on an RF signal modulated with each of the waveforms. The resulting deviations from the simulated values are within the requirements of the HAC standard.

The AIA (Audio Interference Analyzer) is an USB powered electronic sensor to evaluate signals in the frequency range 698MHz - 6 GHz. It contains RMS detector and audio frequency circuits for sampling of the RF envelope.

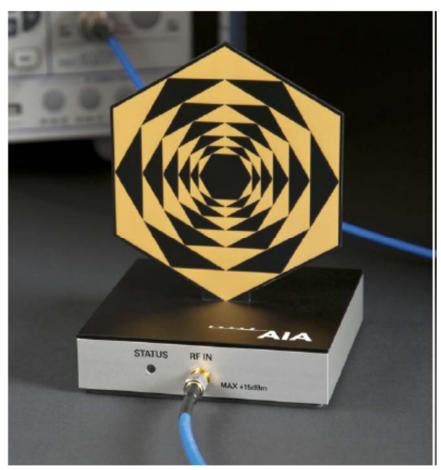


Fig. 5 AIA Front View



#### 9.2 MIF measurement with the AIA

The MIF is measured with the AIA as follows:

- 1. Connect the AIA via USB to the DASY5 PC and verify the configuration settings.
- 2. Couple the RF signal to be evaluated to an AIA via cable or antenna.
- 3. Generate a MIF measurement job for the unknown signal and select the measurement port and timing settings.
- 4. Document the results via the post processor in a report.

## 9.3 Test equipment for the MIF measurement

No.	Name	Туре	Serial Number	Manufacturer
01	Signal Generator	E4438C	MY49071430	Agilent
02	AIA	SE UMS 170 CB	1029	SPEAG
03	BTS	E5515C	MY50263375	Agilent

## 9.4 Test signal validation

The signal generator (E4438C) is used to generate a 1GHz signal with different modulation in the below table based on the ANSI C63.19-2011. The measured MIF with AIA are compared with the target values given in ANSI C63.19-2011 table D.3, D.4 and D5.

Pulse modulation	Target MIF	Measured MIF	Deviation
0.5ms pulse, 1000Hz repetition rate	-0.9 dB	-0.9 dB	0 dB
1ms pulse, 100Hz repetition rate	+3.9 dB	+3.7 dB	0.2 dB
0.1ms pulse, 100Hz repetition rate	+10.1 dB	+10.0 dB	0.1 dB
10ms pulse, 10Hz repetition rate	+1.6 dB	+1.7 dB	0.1 dB
Sine-wave modulation	Target MIF	Measured MIF	Deviation
1 kHz, 80% AM	-1.2 dB	-1.3 dB	0.1 dB
1 kHz, 10% AM	-9.1 dB	-9.0 dB	0.1 dB
1 kHz, 1% AM	-19.1 dB	-18.9 dB	0.2 dB
100 Hz, 10% AM	-16.1 dB	-16.0 dB	0.1 dB
10 kHz, 10% AM	-21.5 dB	-21.6 dB	0.1 dB
Transmission protocol	Target MIF	Measured MIF	Deviation
GSM; full-rate version 2; speech codec/handset low	+3.5 dB	+3.47 dB	0.03 dB
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB	-19.8 dB	0.2 dB
CDMA; speech; SO3; RC3; full frame rate; 8kEVRC	-19.0 dB	-19.1 dB	0.1 dB
CDMA; speech; SO3; RC1; 1/8 <sup>th</sup> frame rate; 8kEVRC	+3.3 dB	+3.44 dB	0.14 dB



## 9.5 DUT MIF results

Typical MIF levels in ANSI C63.19-2011				
Transmission protocol	Modulation interference factor			
GSM; full-rate version 2; speech codec/handset low	+3.5 dB			
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, QPSK)	-15.63 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-9.76 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, QPSK)	-1.62 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-1.44 dB			
CDMA; speech; SO3; RC1; 1/8 <sup>th</sup> frame rate; 8kEVRC	+3.3 dB			

	Measured MIF lev	
Band	Channel	Modulation interference factor
	251	3.49
GSM 850	190	3.51
	128	3.49
	810	3.53
GSM 1900	661	3.52
	512	3.52
	4233	-14.88
WCDMA 850	4182	-15.01
	4132	-15.15
	1513	-15.08
WCDMA 1700	1412	-15.26
	1312	-15.14
	9538	-15.05
WCDMA 1900	9400	-15.06
	9262	-15.10
	19100	-14.23
LTE Band2	18900	-14.65
QPSK —	18700	-14.36
	20300	-14.56
LTE Band4	20175	-14.65
QPSK —	20050	-14.31
	20600	-15.23
LTE Band5	20525	-14.80
QPSK	20450	-14.96
	21350	-14.82
LTE Band7	21100	-14.39
QPSK	20850	-14.47
	23130	-14.7
LTE Band12	23095	-14.86
QPSK —	23060	-14.84
LTE Band13	23230	-14.62
QPSK		
LTE Band17	23800	-14.71
QPSK	23790	-14.70
	23780	-14.93
LTE Band25	41490	-14.52
QPSK	40620	-15.56  ©Copyright. All rights reserved by CT

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	39750	-14.41
LTE Donadoc	41490	-14.83
LTE Band26 — QPSK —	40620	-14.68
QPSK	39750	-15
LTC Danid 44	41490	-1.91
LTE Band41 — QPSK —	40620	-1.74
QPSK	39750	-1.76
LTE DandCC	132572	-14.56
LTE Band66 — QPSK —	132322	-14.08
QPSK	132072	-14.33
LTC Dond?	19100	-10.61
LTE Band2	18900	-10.59
16QAM	18700	-9.98
LTE Decid	20300	-10.72
LTE Band4	20175	-9.81
16QAM	20050	-10.59
	20600	-11.18
LTE Band5	20525	-10.19
16QAM	20450	-9.90
	21350	-9.97
LTE Band7	21100	-10.93
16QAM	20850	-10.93
	23130	-10.56
LTE Band12	23095	-10.14
16QAM	23060	-11.10
LTE Band13 16QAM	23230	-10.32
IOQAIVI	23800	-11.23
LTE Band17	23790	-10.44
16QAM	23780	-10.07
	41490	-10.85
LTE Band25	40620	-9.96
16QAM	39750	-10.85
	41490	-10.60
LTE Band26	40620	-10.38
16QAM	39750	-9.77
	41490	-1.62
LTE Band41	40620	-1.65
16QAM	39750	-1.64
	132572	-9.98
LTE Band66	132372	-10.92
16QAM —	132072	-10.06
	777	2.76
CDMA BC0	384	2.79
CDMA BC0	1013	2.75
	1175	2.75
CDMA BC1	600	2.86
CDIVIA DC I		
	25	2.74
CDMA DO40	684	2.92
CDMA BC10	580	2.9
	476	2.87



## 10 Evaluation for low-power exemption

### 10.1 Product testing threshold

There are two methods for exempting an RF air interface technology from testing. The first method requires evaluation of the MIF for the worst-case operating mode. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is  $\leq$  17 dBm for any of its operating modes. The second method does not require determination of the MIF. The RF emissions testing exemption shall be applied to an RF air interface technology in a device whose peak antenna input power, averaged over intervals  $\leq$  50  $\mu$  s20, is  $\leq$  23 dBm. An RF air interface technology that is exempted from testing by either method shall be rated as M4. The first method is used to be exempt from testing for the RF air interface technology in this report.

### 10.2 Conducted power

Band	Average power (dBm)	MIF (dB)	Sum (dBm)
GSM 850	33.01	+3.49	36.5
GSM 1900	30.14	+3.53	33.67
WCDMA 850	23.89	-15.15	8.74
WCDMA 1700	23.91	-15.26	8.65
WCDMA 1900	23.81	-15.10	8.71
CDMA BC0	24.74	+2.97	27.71
CDMA BC1	24.41	+2.99	27.4
CDMA BC10	24.56	+2.90	27.46

#### 10.3 Conclusion

According to the above table, the sums of average power and MIF for UMTS are less than 17dBm. So it is measured for GSM and CDMA bands. The UMTS bands are exempt from testing and rated as M4.



#### 11 RF TEST PROCEDUERES

#### The evaluation was performed with the following procedure:

- 1) Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2) Position the WD in its intended test position. The gauge block can simplify this positioning.
- 3) Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4) The center sub-grid shall centered on the center of the T-Coil mode axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5) Record the reading.
- 6) Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7) Identify the five contiguous sub-grids around the center sub-grid whose maximum reading is the lowest of all available choices. This eliminates the three sub-grids with the maximum readings. Thus, the six areas to be used to determine the WD's highest emissions are identified.
- 8) Identify the maximum field reading within the non-excluded sub-grids identified in Step 7)
- 9) Evaluate the MIF and add to the maximum steady-state rms field-strength reading to obtain the RF audio interference level..
- Compare this RF audio interference level with the categories and record the resulting WD category rating.



# 12 Measurement Results (E-Field)

Freq	uency	Measured	Dower Drift (dD)	Cotomoni		
MHz	Channel	Value(dBV/m)	Power Drift (dB)	Category		
		GSM 8	50			
848.8	251	33.39	-0.07	<b>M4</b> (see Fig B.1)		
836.6	190	33.21	-0.06	M4 (see Fig B.2)		
824.2	128	32.60	-0.09	M4 (see Fig B.3)		
		<b>GSM</b> 19	000			
1909.8	810	23.66	-0.16	<b>M4</b> (see Fig B.4)		
1880	661	23.45	-0.12	<b>M4</b> (see Fig B.5)		
1850.2	512	25.00	-0.06	<b>M4</b> (see Fig B.6)		
		CDMA E	BC0			
848.31	777	25.19	0.01	<b>M4</b> (see Fig B.7)		
836.52	384	25.43	0.01	<b>M4</b> (see Fig B.8)		
824.7	1013	25.13	-0.12	<b>M4</b> (see Fig B.9)		
		CDMA E	BC1			
1908.75	1175	17.27	0.01	<b>M4</b> (see Fig B.10)		
1880	600	17.76	0.09	<b>M4</b> (see Fig B.11)		
1851.25	25	18.42	0.06	<b>M4</b> (see Fig B.12)		
	CDMA BC10					
832.1	684	24.63	0.10	<b>M4</b> (see Fig B.13)		
820.5	580	24.80	-0.04	<b>M4</b> (see Fig B.14)		
817.9	476	24.40	-0.14	<b>M4</b> (see Fig B.15)		

## 13 ANSIC 63.19-2011 LIMITS

## WD RF audio interference level categories in logarithmic units

Emission categories	< 960 MHz			
	E-field emissions			
Category M1	50 to 55	dB (V/m)		
Category M2	45 to 50	dB (V/m)		
Category M3	40 to 45	dB (V/m)		
Category M4	< 40	dB (V/m)		
Emission categories	>96	0 MHz		
	E-field 6	emissions		
Category M1	40 to 45	dB (V/m)		
Category M2	35 to 40	dB (V/m)		
Category M3	30 to 35	dB (V/m)		
Category M4	< 30	dB (V/m)		



# **14 MEASUREMENT UNCERTAINTY**

No.	Error source	Туре	Uncertainty Value(%)	Prob. Dist.	k	c <sub>i</sub> E	Standard Uncertainty (%) $u_i^{'}$ (%)E	Degree of freedom V <sub>eff</sub> or <i>v</i> <sub>i</sub>
Meas	urement System							
1	Probe Calibration	В	5.	N	1	1	5.1	∞
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	2.7	∞
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	9.5	∞
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1.4	∞
5	Linearity	В	4.7	R	$\sqrt{3}$	1	2.7	∞
6	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1.2	∞
7	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	0.6	∞
8	Readout Electronics	В	0.3	N	1	1	0.3	∞
9	Response Time	В	0.8	R	$\sqrt{3}$	1	0.5	∞
10	Integration Time	В	2.6	R	$\sqrt{3}$	1	1.5	∞
11	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1.7	∞
12	RF Reflections	В	12.0	R	$\sqrt{3}$	1	6.9	∞
13	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.7	∞
14	Probe Positioning	А	4.7	R	$\sqrt{3}$	1	2.7	∞
15	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	0.6	∞
Test	Test Sample Related							
16	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	2.7	∞
17	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	0.6	∞
18	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1.4	∞
19	Power Drift	В	5.0	R	$\sqrt{3}$	1	2.9	∞



20	AIA measurement	В	12	R	$\sqrt{3}$	1	6.9	∞
Pha	Phantom and Setup related							
21	Phantom Thickness	В	2.4	R	$\sqrt{3}$	1	1.4	8
Com	Combined standard uncertainty(%) 16.2							
	nded uncertainty idence interval of 95 %)	ι	$u_e = 2u_c$	Z	k=:	2	32.4	

## **15 MAIN TEST INSTRUMENTS**

**Table 1: List of Main Instruments** 

No.	Name	Туре	Serial Number	Calibration Date	Valid Period
01	Signal Generator	E4438C	MY49071430	January 13,2017	One Year
02	Power meter	NRVD	102083	Santambar 22 2016	One year
03	Power sensor	NRV-Z5	100595	September 22,2016	One year
04	Amplifier	60S1G4	0331848	No Calibration Re	quested
05	E-Field Probe	ER3DV6	2428	January 19, 2017	One year
06	HAC Dipole	CD835V3	1023	August 31, 2016	One year
07	HAC Dipole	CD1880V3	1018	August 31, 2016	One year
08	BTS	E5515C	MY50263375	January 16, 2017	One year
09	DAE	SPEAG DAE4	777	August 22, 2016	One year
10	AIA	SE UMS 170 CB	1029	No Calibration Re	quested

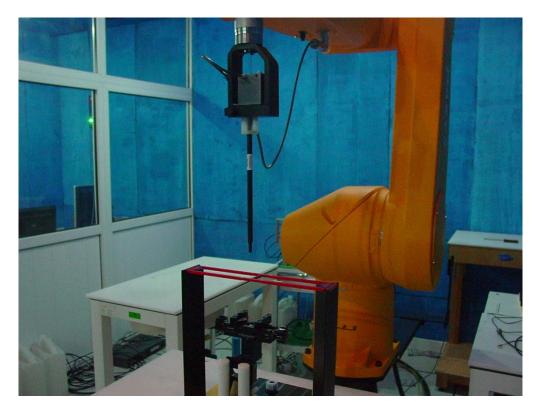
## **16 CONCLUSION**

The HAC measurement indicates that the EUT complies with the HAC limits of the ANSIC63.19-2011. The total M-rating is M4.

\*\*\*END OF REPORT BODY\*\*\*



# ANNEX A TEST LAYOUT



Picture A1:HAC RF System Layout



## ANNEX B TEST PLOTS

## HAC RF E-Field GSM 850 High

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

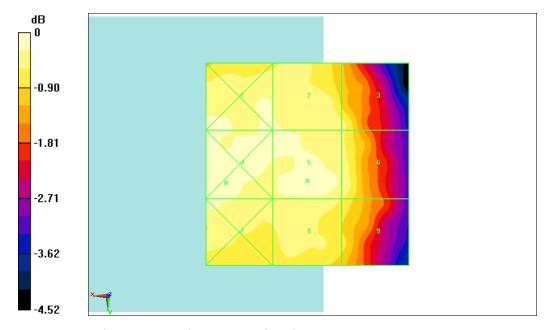
Reference Value = 22.60 V/m; Power Drift = -0.01 dB

Applied MIF = 3.48 dB

RF audio interference level = 28.68 dBV/m

**Emission category: M4** 

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
28.61 dBV/m	28.53 dBV/m	28.26 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 <b>M4</b>
28.77 dBV/m	28.68 dBV/m	28.43 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
28.6 dBV/m	28.45 dBV/m	28.17 dBV/m



0 dB = 27.44 V/m = 28.77 dBV/m

Fig B.1 HAC RF E-Field GSM 850 High



#### HAC RF E-Field GSM 850 Middle

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

## E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

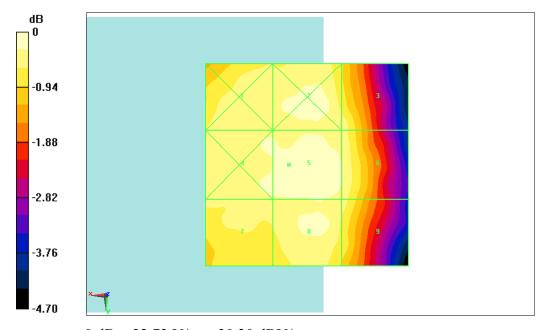
Reference Value = 27.34 V/m; Power Drift = -0.00 dB

Applied MIF = 3.50 dB

RF audio interference level = 30.30 dBV/m

**Emission category: M4** 

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
29.93 dBV/m	30.1 dBV/m	29.85 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 <b>M4</b>
30.07 dBV/m	30.3 dBV/m	30 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
29.95 dBV/m	30.08 dBV/m	29.83 dBV/m



0 dB = 32.73 V/m = 30.30 dBV/m

Fig B.2 HAC RF E-Field GSM 850 Middle



#### HAC RF E-Field GSM 850 Low

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

## E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

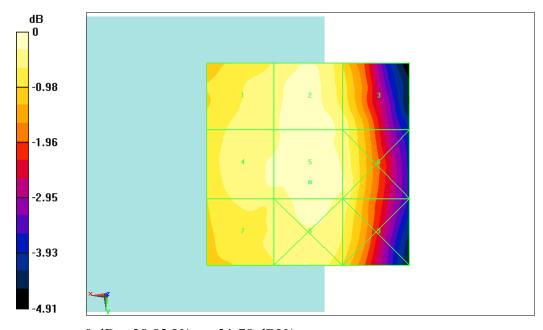
Reference Value = 32.84 V/m; Power Drift = -0.05 dB

Applied MIF = 3.49 dB

RF audio interference level = 31.78 dBV/m

**Emission category: M4** 

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
31.4 dBV/m	31.62 dBV/m	31.33 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
31.53 dBV/m	31.78 dBV/m	31.5 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 <b>M4</b>
31.27 dBV/m	31.69 dBV/m	31.34 dBV/m



0 dB = 38.83 V/m = 31.78 dBV/m

Fig B.3 HAC RF E-Field GSM 850 Low



## HAC RF E-Field GSM 1900 High

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

## E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

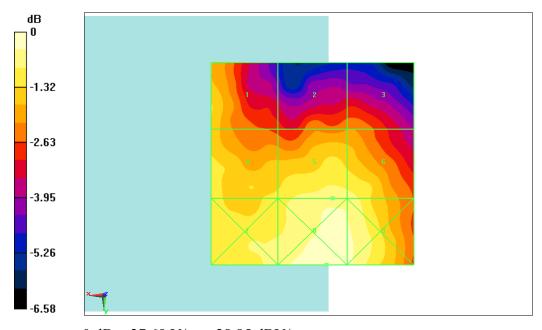
Reference Value = 18.29 V/m; Power Drift = 0.14 dB

Applied MIF = 3.41 dB

RF audio interference level = 28.25 dBV/m

**Emission category: M4** 

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
27.58 dBV/m	26.65 dBV/m	26.68 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 <b>M4</b>
27.73 dBV/m	28.25 dBV/m	28.19 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 <b>M4</b>
28.24 dBV/m	28.85 dBV/m	28.55 dBV/m



0 dB = 27.69 V/m = 28.85 dBV/m

Fig B.4 HAC RF E-Field GSM 1900 High



#### HAC RF E-Field GSM 1900 Middle

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

## E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

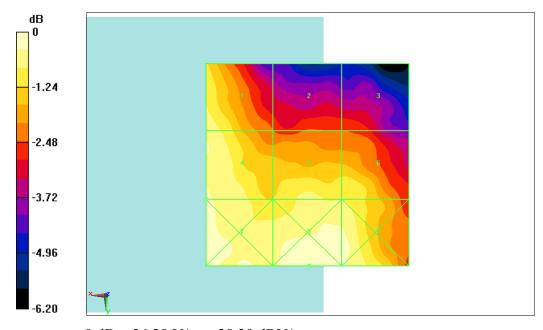
Reference Value = 17.11 V/m; Power Drift = -0.01 dB

Applied MIF = 3.47 dB

RF audio interference level = 28.06 dBV/m

**Emission category: M4** 

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
27.86 dBV/m	25.96 dBV/m	25.92 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 <b>M4</b>
28.06 dBV/m	27.8 dBV/m	27.58 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 <b>M4</b>
28.32 dBV/m	28.39 dBV/m	28.13 dBV/m



0 dB = 26.28 V/m = 28.39 dBV/m

Fig B.5 HAC RF E-Field GSM 1900 Middle



#### HAC RF E-Field GSM 1900 Low

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

## E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

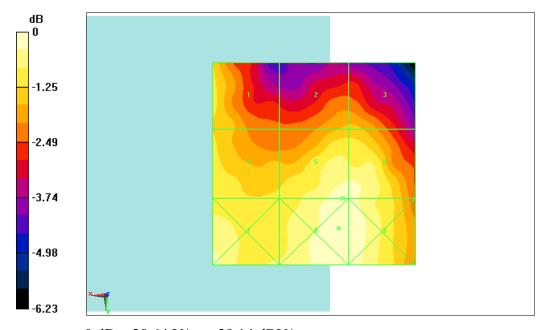
Reference Value = 19.66 V/m; Power Drift = -0.14 dB

Applied MIF = 3.48 dB

RF audio interference level = 28.86 dBV/m

**Emission category: M4** 

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
28.16 dBV/m	27.65 dBV/m	27.65 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 <b>M4</b>
28.16 dBV/m	28.86 dBV/m	28.83 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 <b>M4</b>
28.96 dBV/m	29.14 dBV/m	29.07 dBV/m



0 dB = 28.64 V/m = 29.14 dBV/m

Fig B.6 HAC RF E-Field GSM 1900 Low



## HAC RF E-Field CDMA BC0 High

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: CDMA 835; Frequency: 848.31 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 17.23 V/m; Power Drift = -0.10 dB

Applied MIF = 3.00 dB

RF audio interference level = 26.55 dBV/m

MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
27.35 dBV/m	26.55 dBV/m	25.42 dBV/m
Grid 4 <b>M4</b>	Grid 5 <b>M4</b>	Grid 6 <b>M4</b>
27.43 dBV/m	26.54 dBV/m	25.4 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
27.17 dBV/m	26.18 dBV/m	25.21 dBV/m

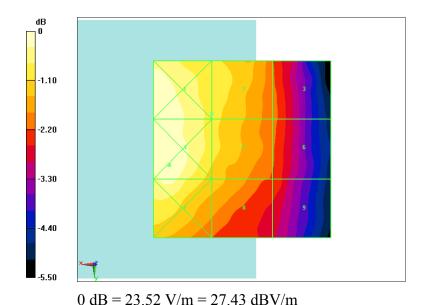


Fig B.7 HAC RF E-Field CDMA BC0 High



#### HAC RF E-Field CDMA BC0 Middle

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: CDMA 835; Frequency: 836.52 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

# E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 15.92 V/m; Power Drift = -0.12 dB

Applied MIF = 2.97 dB

RF audio interference level = 25.97 dBV/m

MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
26.99 dBV/m	25.97 dBV/m	24.66 dBV/m
Grid 4 <b>M4</b>	Grid 5 <b>M4</b>	Grid 6 <b>M4</b>
27.07 dBV/m	25.96 dBV/m	24.51 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
26.8 dBV/m	25.71 dBV/m	24.13 dBV/m

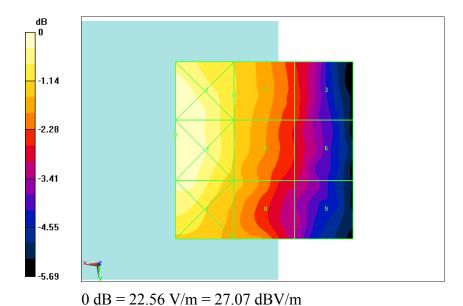


Fig B.8 HAC RF E-Field CDMA BC0 Middle



#### HAC RF E-Field CDMA BC0 Low

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: CDMA 835; Frequency: 824.7 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

# E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 14.99 V/m; Power Drift = -0.16 dB

Applied MIF = 2.96 dB

RF audio interference level = 25.61 dBV/m

MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
26.88 dBV/m	25.59 dBV/m	24.01 dBV/m
Grid 4 <b>M4</b>	Grid 5 <b>M4</b>	Grid 6 <b>M4</b>
26.87 dBV/m	25.61 dBV/m	23.97 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
26.56 dBV/m	25.22 dBV/m	23.59 dBV/m

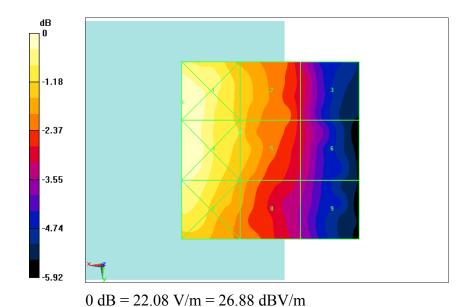


Fig B.9 HAC RF E-Field CDMA BC0 Low



## HAC RF E-Field CDMA BC1 High

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Ambient Temperature: 22.0°C

Communication System: CDMA 1900; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2272;ConvF(1, 1, 1)

# E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

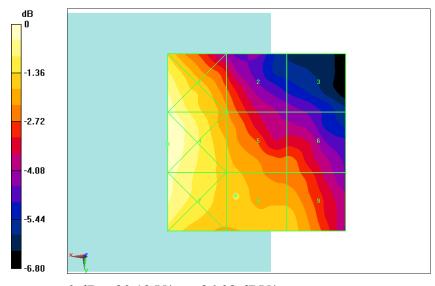
Reference Value = 12.17 V/m; Power Drift = -0.03 dB

Applied MIF = 2.93 dB

RF audio interference level = 24.75 dBV/m

MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 <b>M4</b>
25.89 dBV/m	23.92 dBV/m	21.86 dBV/m
Grid 4 <b>M4</b>	Grid 5 <b>M4</b>	Grid 6 <b>M4</b>
26.08 dBV/m	24.53 dBV/m	23.64 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
25.84 dBV/m	24.75 dBV/m	24.49 dBV/m



0 dB = 20.13 V/m = 26.08 dBV/m

Fig B.10 HAC RF E-Field CDMA BC1 High